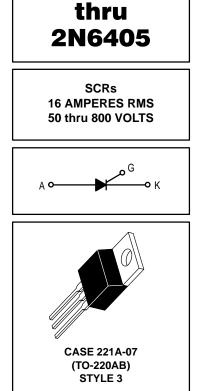
Silicon Controlled Rectifiers Reverse Blocking Triode Thyristors

... designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supplies; or wherever half-wave silicon gate-controlled, solid-state devices are needed.

- Glass Passivated Junctions with Center Gate Geometry for Greater Parameter • Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Blocking Voltage to 800 Volts



2N6400

Rating	Rating Symbol		Unit	
Peak Repetitive Forward and Reverse Voltage(1) (Gate Open, $T_J = 25$ to 125° C) 2N6400 2N6401 2N6402 2N6403 2N6404 2N6404 2N6405	VDRM, VRRM	50 100 200 400 600 800	Volts	
RMS On–State Current (T _C = 90°C)	IT(RMS)	16	Amps	
Average On-State Current	IT(AV)	10	Amps	
Peak Non-Repetitive Forward Surge Current (1/2 Cycle, Sine Wave, 60 Hz, TJ = 125°C)	ITSM	160	Amps	
Circuit Fusing (t = 8.3 ms)	l ² t	145	A ² s	
Forward Peak Gate Power	PGM	20	Watts	
Forward Average Gate Power	P _{G(AV)}	0.5	Watt	
Forward Peak Gate Current	IGM	2	Amps	
Operating Junction Temperature Range	Тj	-40 to +125	°C	
Storage Temperature Range	T _{stg}	-40 to +150	°C	
HERMAL CHARACTERISTICS				
Characteristic	Symbol	Max	Unit	

	bol Max	Unit
Thermal Resistance, Junction to Case R ₀ J	C 1.5	°C/W

*Indicates JEDEC Registered Data.

1. VDRM and VRRM for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Devices listed in bold, italic are Motorola preferred devices. Preferred devices are Motorola recommended choices for future use and best overall value.



2N6400 thru 2N6405

ELECTRICAL CHARACTERISTICS (T_C = 25° C unless otherwise noted.)

Characteristic		Symbol	Min	Тур	Max	Unit
*Peak Forward or Reverse Blocking Current (V _{AK} = Rated V _{DRM} or V _{RRM} , Gate Open)	TJ = 25°C TJ = 125°C	IDRM, IRRM	_		10 2	μA mA
*Peak On–State Voltage (I _{TM} = 32 A Peak, Pulse Width ≤ 1 ms, Duty Cy	rcle ≤ 2%)	V _{TM}	—	—	1.7	Volts
*Gate Trigger Current (Continuous dc) (V _D = 12 Vdc, R _L = 50 Ohms)		IGT	—	5	30	mA
*Gate Trigger Voltage (Continuous dc) (V _D = 12 Vdc, R _L = 50 Ohms) (V _D = Rated V _{DRM} , R _L = 50 Ohms)	$T_{C} = 25^{\circ}C$ $T_{C} = -40^{\circ}C$ $T_{C} = +125^{\circ}C$	VGT	 	0.7 	1.5 2.5 —	Volts
*Holding Current (V _D = 12 Vdc, Gate Open)	$T_C = 25^{\circ}C$ $*T_C = -40^{\circ}C$	Н	—	6 —	40 60	mA
Turn-On Time (I _{TM} = 16 A, I _{GT} = 40 mAdc, V _D = Rated V _{DRN}	V)	tgt	—	1	_	μs
Turn-Off Time (I_{TM} = 16 A, I_R = 16 A, V_D = Rated V_{DRM})	T _C = 25°C T _J = +125°C	tq		15 35		μs
Critical Rate–of–Rise of Off-State Voltage (V _D = Rated V _{DRM} , Exponential Waveform)	TJ = +125°C	dv/dt	—	50	_	V/µs

*Indicates JEDEC Registered Data.

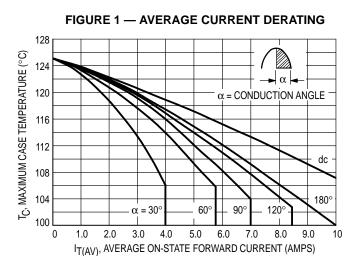
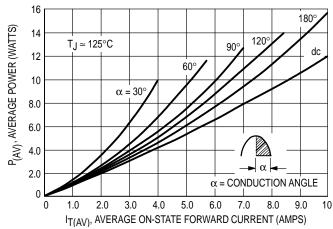
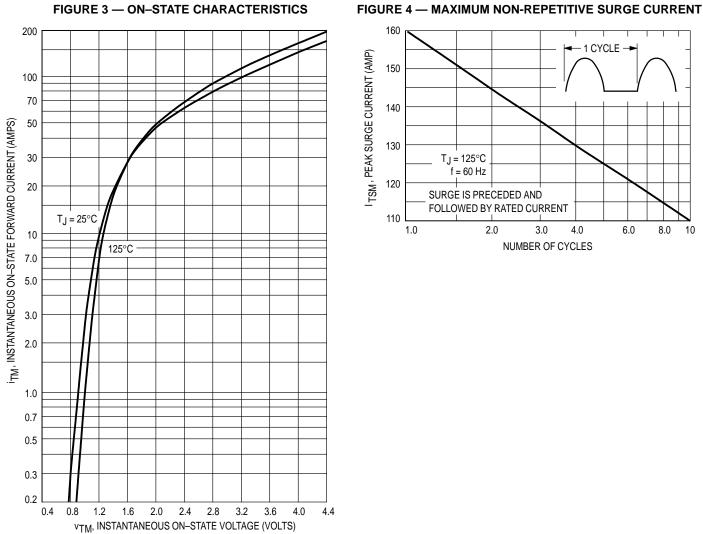


FIGURE 2 — MAXIMUM ON-STATE POWER DISSIPATION





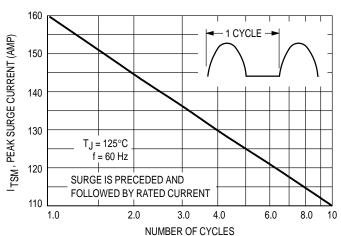
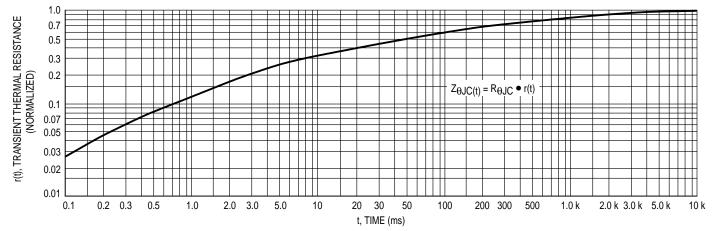


FIGURE 5 — THERMAL RESPONSE



TYPICAL CHARACTERISTICS

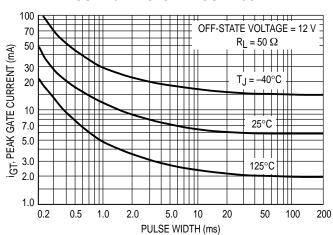
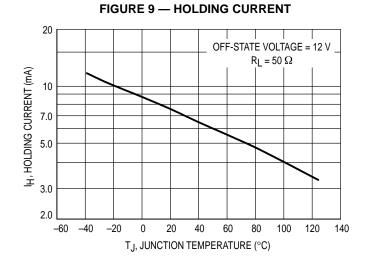


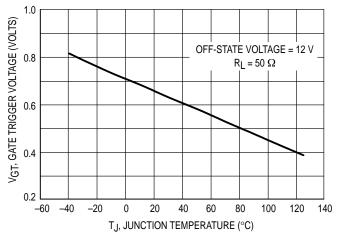
FIGURE 6 — PULSE TRIGGER CURRENT

20 OFF-STATE VOLTAGE = 12 V IGT, GATE TRIGGER CURRENT (mA) $R_L = 50 \Omega$ 10 7.0 5.0 3.0 2.0 -60 -40 -20 0 20 40 60 80 100 120 140 TJ, JUNCTION TEMPERATURE (°C)

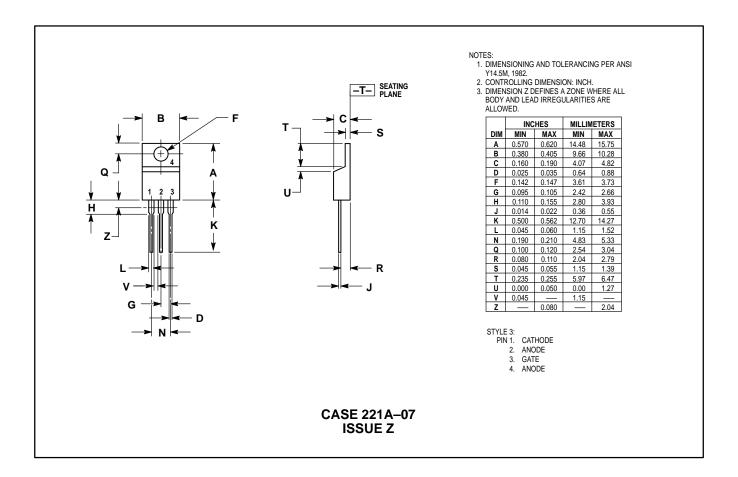
FIGURE 7 — GATE TRIGGER CURRENT







PACKAGE DIMENSIONS



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